1N4245/US thru 1N4249/US

SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 5083, REV. A

JAN SJ JANTX SX JANTXV SV

Standard Recovery Rectifier

Features / Benefits:

- ✓ Hermetic, non-cavity glass package
- ✓ Metallurgically bonded
- ✓ JAN/ JANTX/ JANTXV available per MIL-PRF-19500/286

Maximum Ratings:

- ✓ Operating and Storage Temperature: -65°C to +175°C
- ✓ Thermal Resistance: 42 °C (junction to lead)
- ✓ Forward surge current

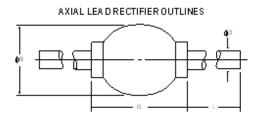
TYPE NUMBER	PEAK INVERSE VOLTAGE	MAX. AVG. DC OUTPUT CURRENT			Max. F Forw Volt/ (Puls	ARD AGE	PEAK 1 CYCLE SURGE CURRENT	MAXIMUM REVERSE RECOVERY TIME	THERM. RESIS. R _{0JL} d=.375"
		Amps	μAr	nps					
	Volts	55°C	25°C	150°C	V	Α	Amps	nsec	°C/W
1N4245/US 1N4246/US 1N4247/US 1N4248/US 1N4249/US	200 400 600 800 1000	1.0	1.0	150	1.3	3.0	25	5000	42

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MECHANICAL DIMENSIONS In Inches / (mm)

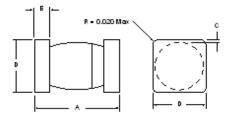


Note: Cathode side of device is indicated by a dark band marked on body.

PACKAGE STYLE	DIMENSIONS - INCHES / MILLIMETERS					
STILL	¢⊖	۹D	G	L		
103	.065/.150	.027/.033	.140/.250	1.0/1.50		

1.65/3.81	.69/.84	3.56/6.35	25.4/38.1

MELF PACKAGE OUTLINES





Note: Cathode side of device is indicated by a dark band marked on body.

PACKAGE STYLE	DIMENSIONS - INCHES / MILLIMETERS					
MELF-1	A	B	C	D		
	.168/.230	0.019/.028	.003 Min	.091/.128		
	4.2/5.9	.48/.72	.076 Min	2.311/ 3.25:		

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